



2SB1296/2SD1936

AF Amplifier Applications

Applications

- AF power amplifier, medium-speed switching, small-sized motor drivers.

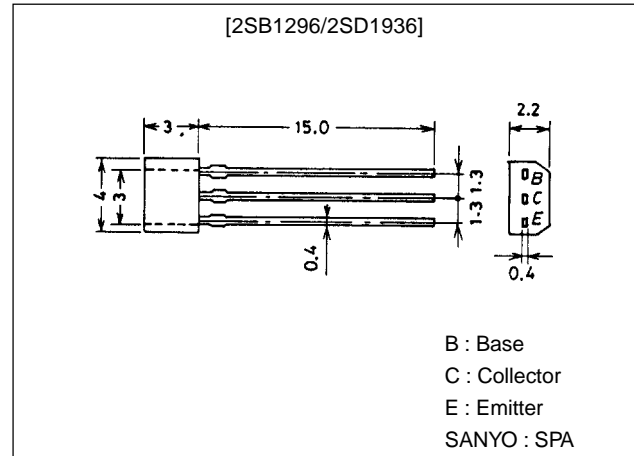
Features

- Large current capacity.
- Low collector to emitter saturation voltage.
- Wide ASO.

Package Dimensions

unit:mm

2033



() : 2SB1296

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CB0}		(-)15	V
Collector-to-Emitter Voltage	V_{CEO}		(-)15	V
Emitter-to-Base Voltage	V_{EBO}		(-)5	V
Collector Current	I_C		(-)0.8	A
Collector Current (Pulse)	I_{CP}		(-)3	A
Collector Dissipation	P_C		300	mW
Junction Temperature	T_J		150	°C
Storage Temperature	T_{stg}		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)12V, I_E = 0$			(-)100	nA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4V, I_C = 0$			(-)100	nA
DC Current Gain	h_{FE1}	$V_{CE} = (-)2V, I_C = (-)50mA$	140*		(560)*	
	h_{FE2}	$V_{CE} = (-)2V, I_C = (-)800mA$	80		800*	

* : The 2SB1296/2SD1936 are classified by 50mA h_{FE} as follows :

2SB1296 140 S 280 200 T 400 280 U 560

2SB1936 140 S 280 200 T 400 280 U 560 400 V 800

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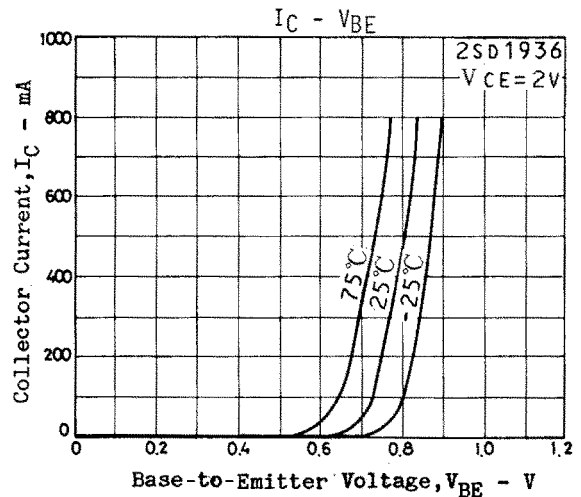
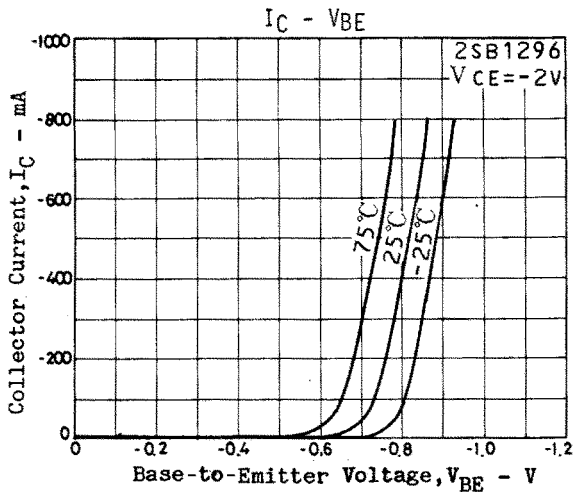
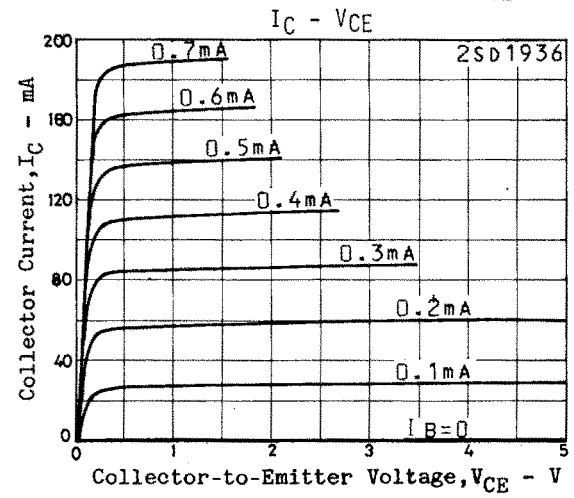
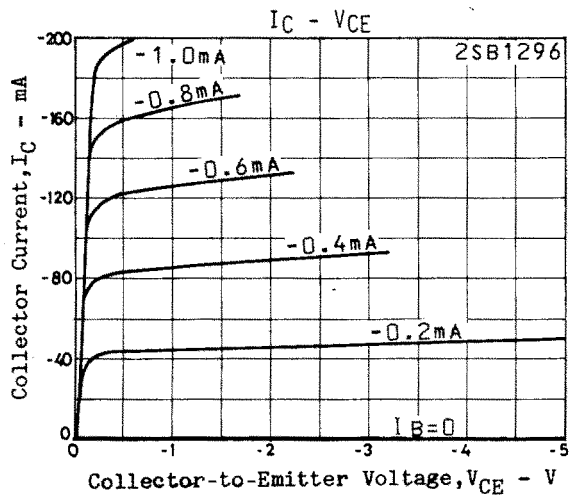
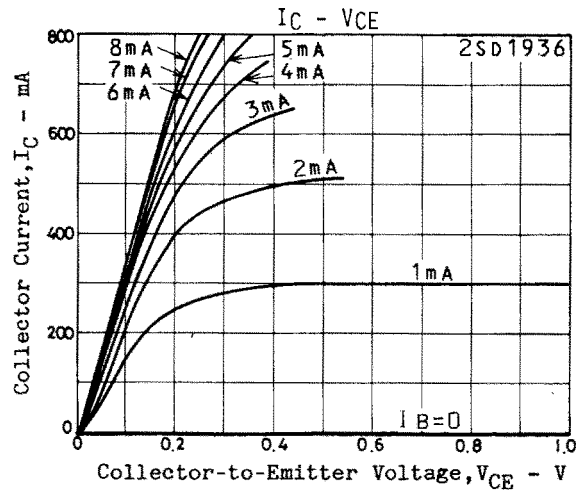
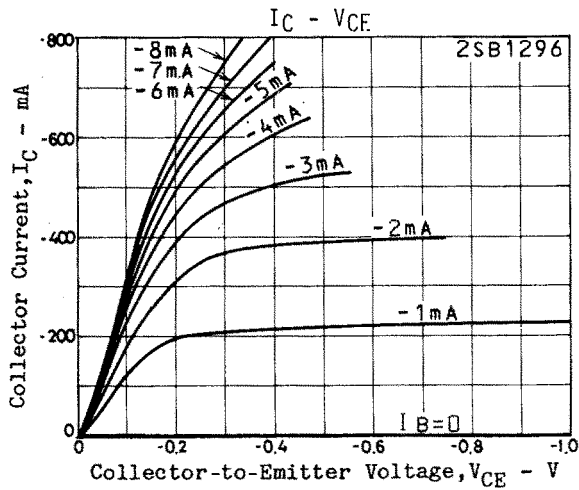
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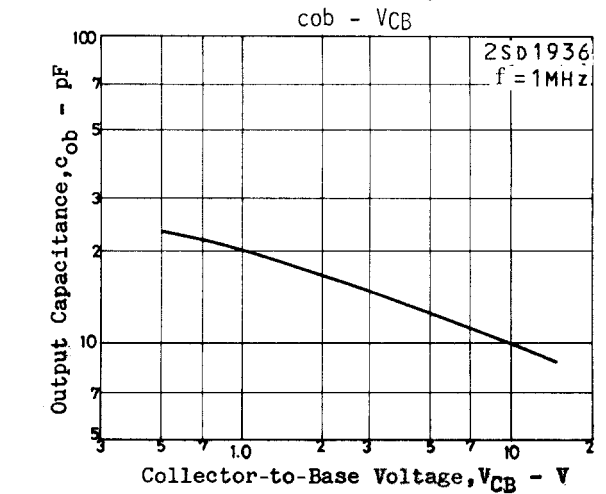
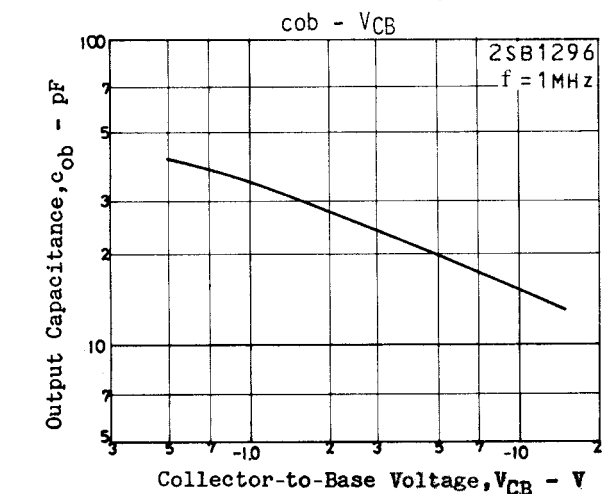
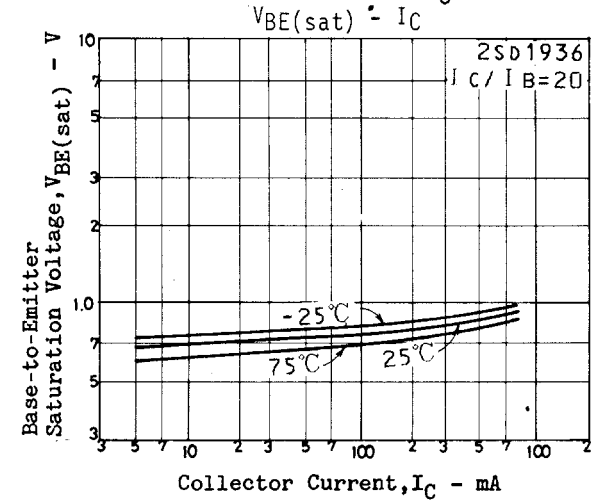
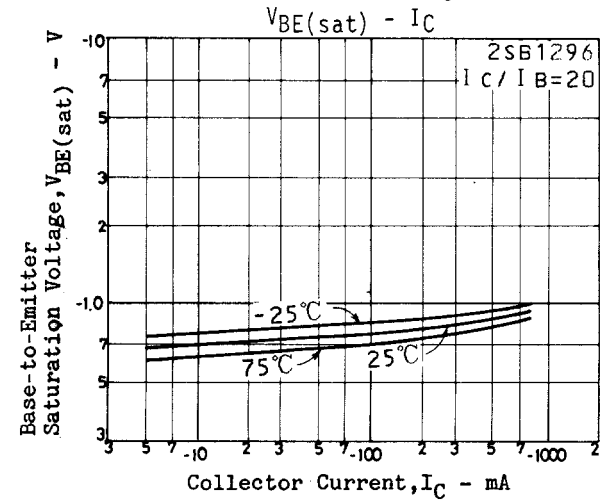
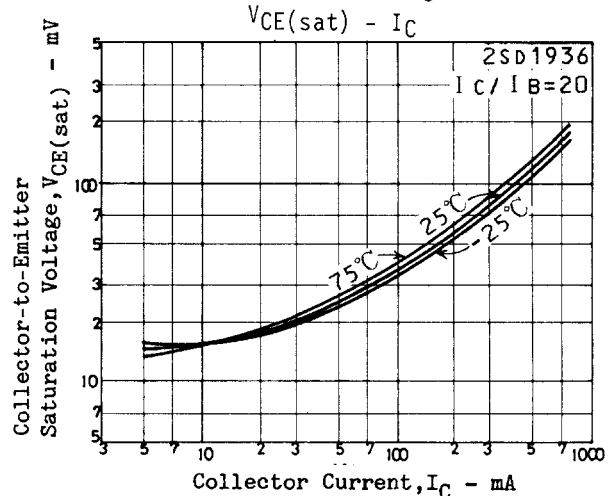
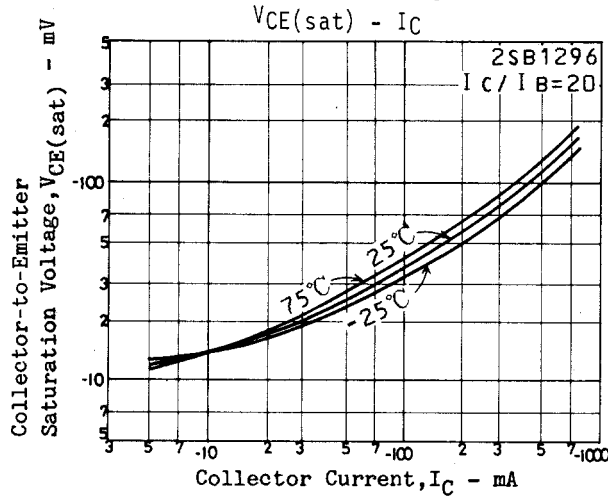
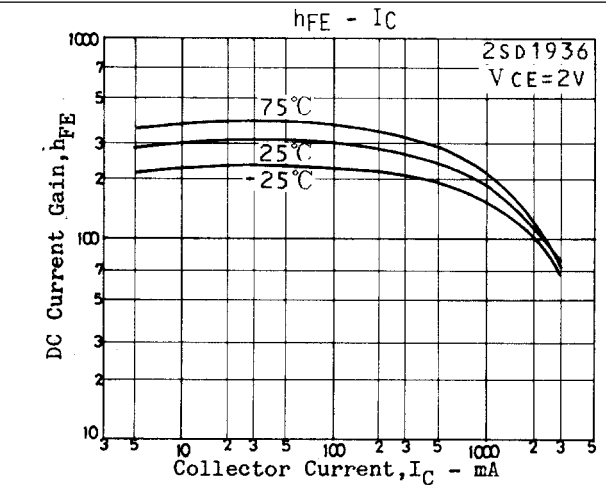
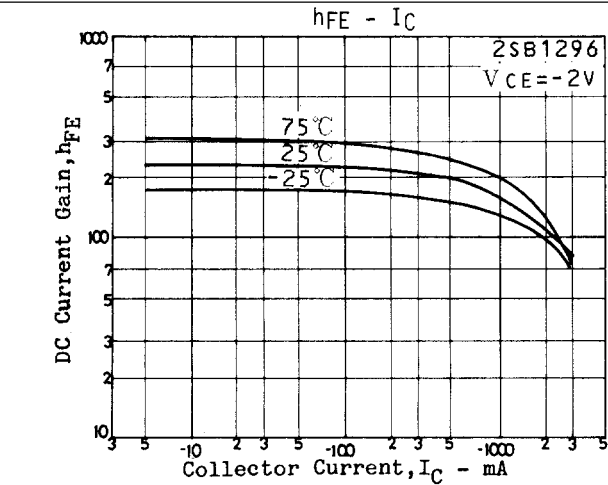
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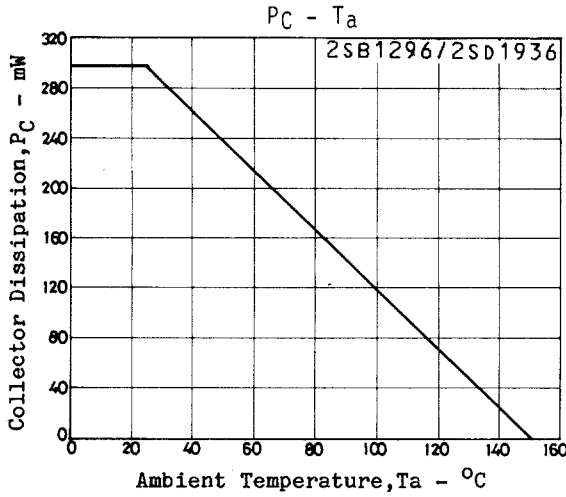
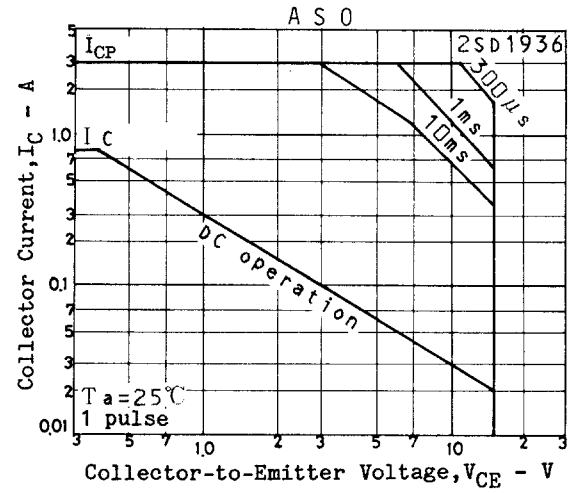
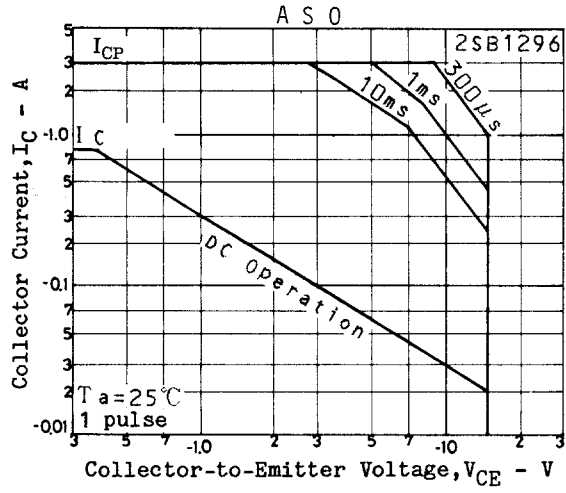
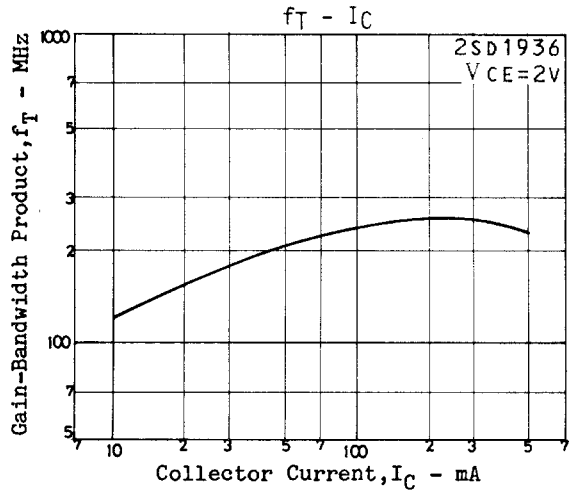
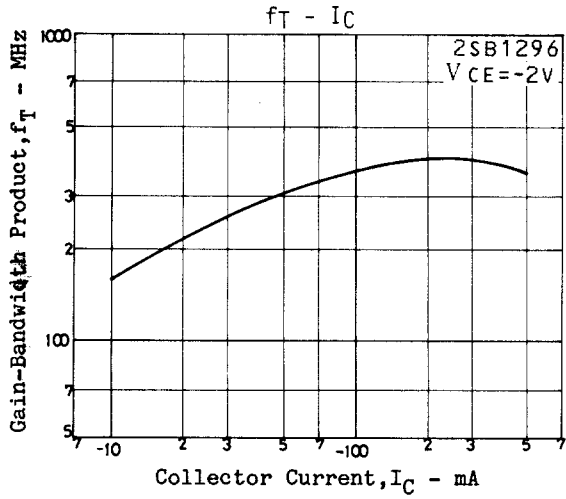
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Gain-Bandwidth Product	f_T	$V_{CE}=(-)2V, I_C=(-)50mA$		(300)		MHz
Output Capacitance	C_{ob}	$V_{CB}=(-)10V, f=1MHz$		200		MHz
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)1}$	$I_C=(-)5mA, I_B=(-)0.5mA$		(-10)	(-25)	mV
	$V_{CE(sat)2}$	$I_C=(-)400mA, I_B=(-)20mA$		(-100)	(-200)	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=(-)400mA, I_B=(-)20mA$		(-0.9)	(-1.2)	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)10\mu A, I_E=0$	(-15)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-15)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)10\mu A, I_C=0$	(-5)			V



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